

RF Power MOSFET Transistor 5W, 100-500 MHz, 28V

Rev. V1

Features

- N-channel enhancement mode device
- DMOS structure
- Lower capacitances for broadband operation
- Common source configuration
- Lower noise floor
- 100 MHz to 500 MHz operation

ABSOLUTE MAXIMUM RATINGS AT 25° C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	V
Gate-Source Voltage	V_{GS}	20	V
Drain-Source Current	I_{DS}	1.4	A
Power Dissipation	P_D	14.4	W
Junction Temperature	T_J	200	°C
Storage Temperature	T_{STG}	-55 to +150	°C
Thermal Resistance	θ_{JC}	12.1	°C/W

TYPICAL DEVICE IMPEDANCES

F (MHz)	Z_{IN} (Ω)	Z_{LOAD} (Ω)
100	15.0-j8.0	35.0+j55.0
300	8.0-j43.0	29.0+j40.0
500	4.0-j29.0	28.0-j29.0
$V_{DD}=28V$, $I_{DQ}=50$ Ma, $P_{OUT}=100.0$ W		

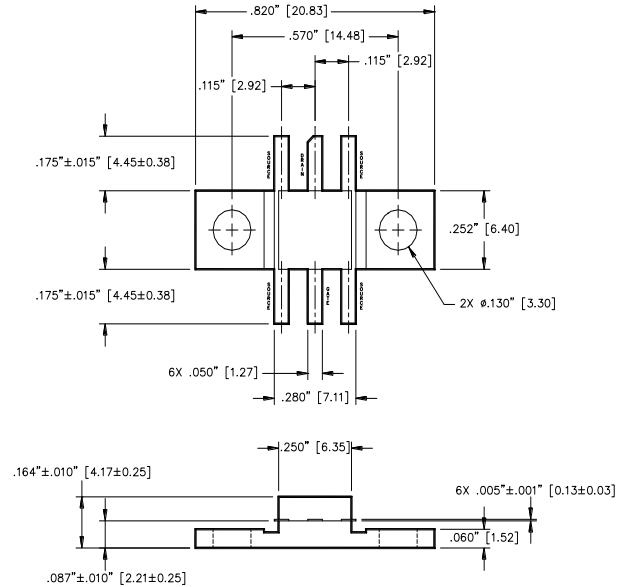
Z_{IN} is the series equivalent input impedance of the device from gate to source.

Z_{LOAD} is the optimum series equivalent load impedance as measured from drain to drain.

ELECTRICAL CHARACTERISTICS AT 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Drain-Source Breakdown Voltage	BV_{DSS}	65	-	V	$V_{GS} = 0.0$ V , $I_{DS} = 2.0$ mA
Drain-Source Leakage Current	I_{DSS}	-	1.0	mA	$V_{DS} = 28.0$ V , $V_{GS} = 0.0$ V
Gate-Source Leakage Current	I_{GSS}	-	1.0	μ A	$V_{GS} = 20.0$ V , $V_{DS} = 0.0$ V
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	$V_{DS} = 10.0$ V , $I_{DS} = 10.0$ mA
Forward Transconductance	G_M	80	-	S	$V_{DS} = 10.0$ V , $I_{DS} = 1.0$ mA , $\Delta V_{GS} = 1.0$ V, 80 μ s Pulse
Input Capacitance	C_{ISS}	-	7.0	pF	$V_{DS} = 28.0$ V , F = 1.0 MHz
Output Capacitance	C_{OSS}	-	5	pF	$V_{DS} = 28.0$ V , F = 1.0 MHz
Reverse Capacitance	C_{RSS}	-	2.4	pF	$V_{DS} = 28.0$ V , F = 1.0 MHz
Power Gain	G_P	10	-	dB	$V_{DD} = 28.0$ V , $I_{DQ} = 50$ mA, $P_{OUT} = 5.0$ W F =500 MHz
Drain Efficiency	η_D	50	-	%	$V_{DD} = 28.0$ V , $I_{DQ} = 50$ mA, $P_{OUT} = 5.0$ W F =500 MHz
Load Mismatch Tolerance	VSWR-T	-	20:1	-	$V_{DD} = 28.0$ V , $I_{DQ} = 50$ mA, $P_{OUT} = 5.0$ W F =500MHz

Package Outline

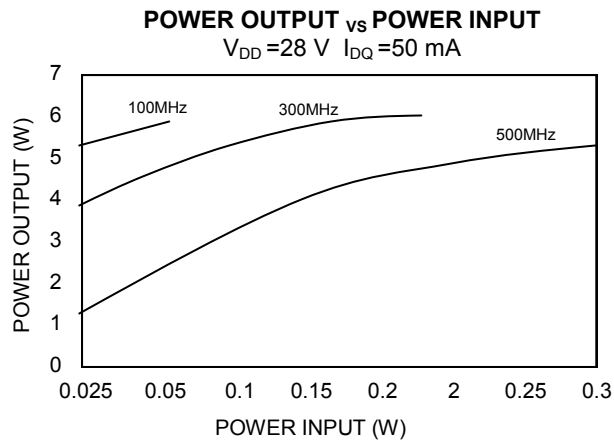
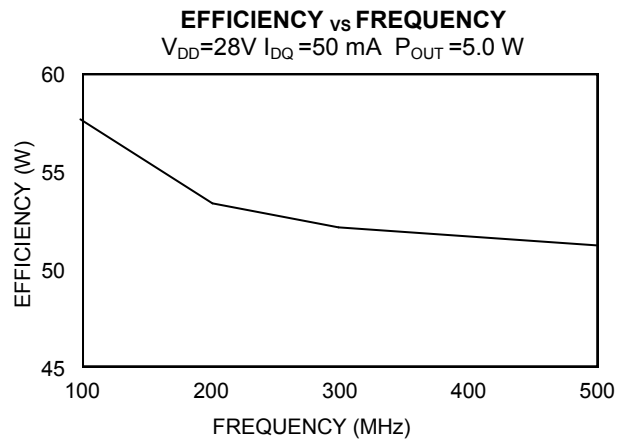
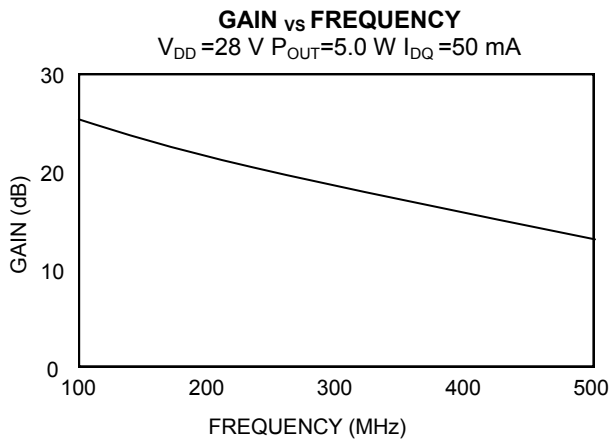
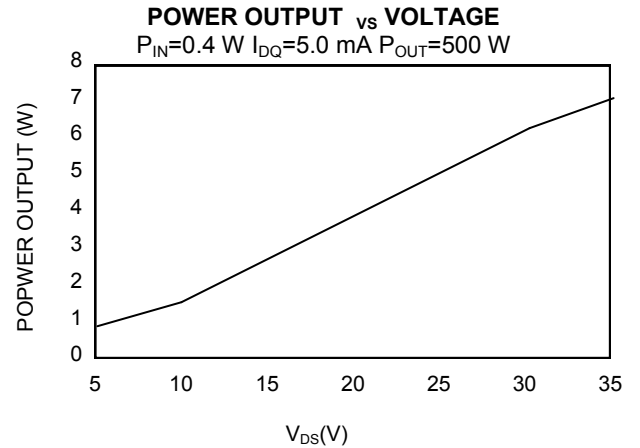
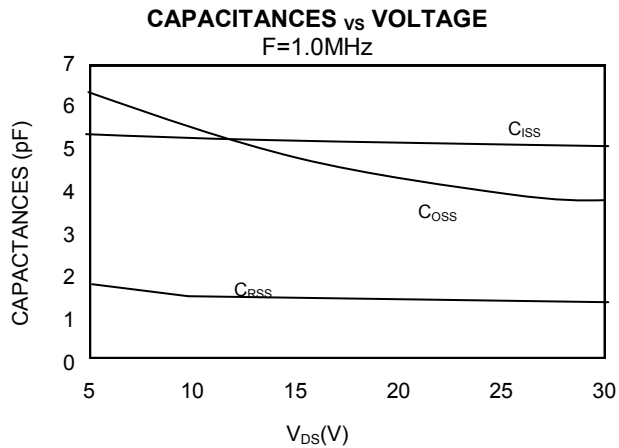


UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES $\pm .005$ \"/>

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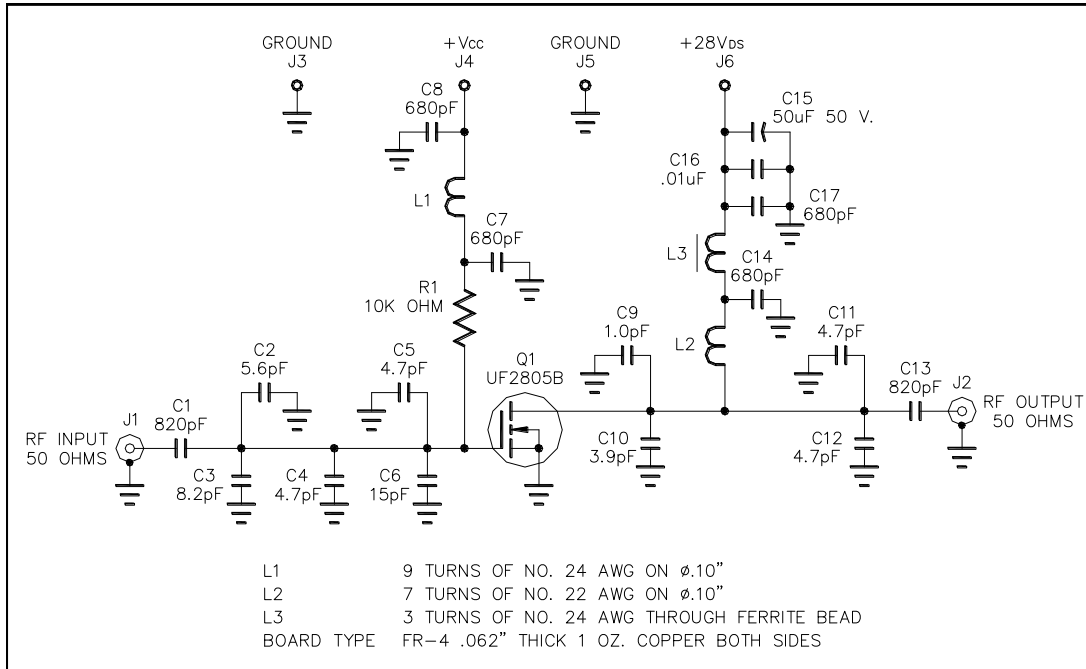
Typical Broadband Performance Curves



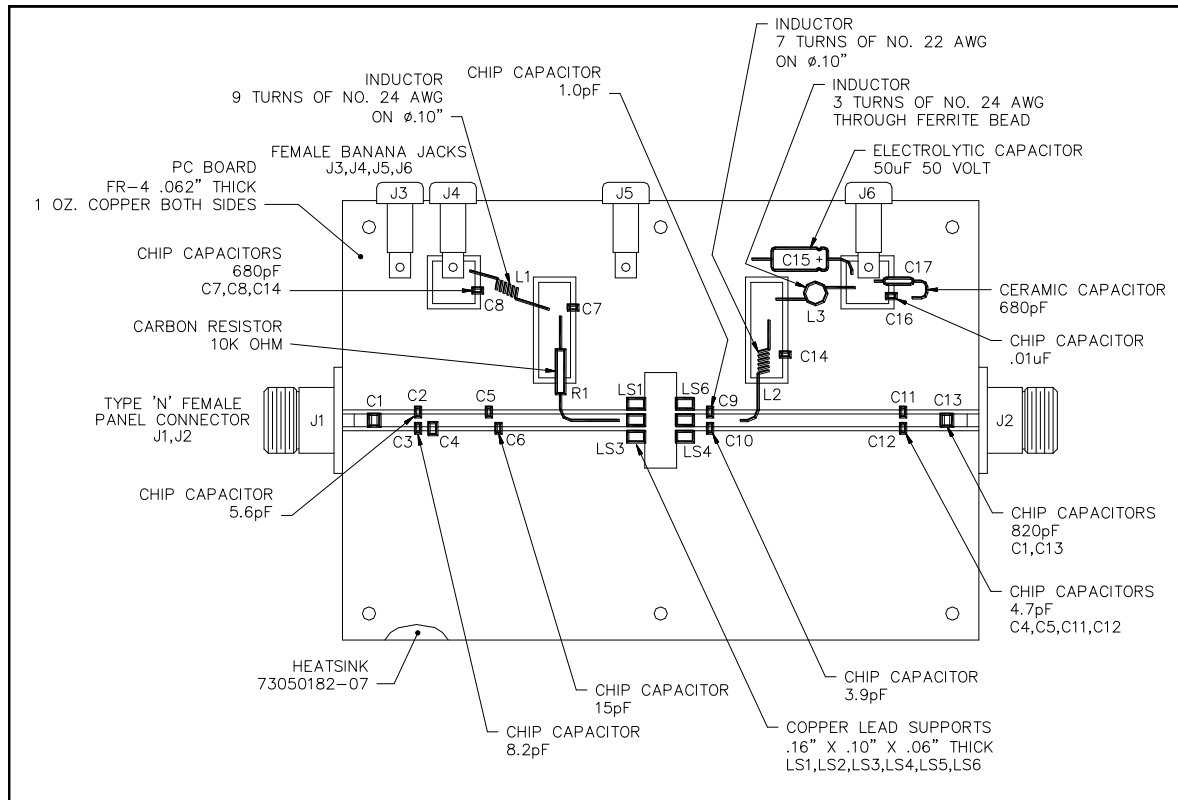
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TEST FIXTURE SCHEMATIC



TEST FIXTURE ASSEMBLY



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